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SCDS171A-JULY 2004-REVISED MARCH 2005

#### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- High-Bandwidth Data Path (up to 500 MHz (1))
- 5-V Tolerant I/Os With Device Powered Up or Powered Down
- Low and Flat ON-State Resistance (r<sub>on</sub>)
   Characteristics Over Operating Range (r<sub>on</sub> = 5 Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports
  - 0- to 5-V Switching With 3.3-V V<sub>CC</sub>
  - 0- to 3.3-V Switching With 2.5-V V<sub>CC</sub>
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low Input/Output Capacitance Minimizes Loading and Signal Distortion (C<sub>io(OFF)</sub> = 4 pF Typ)
- Fast Switching Frequency (f<sub>OF</sub> = 20 MHz Max)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I<sub>CC</sub> = 1 mA Typ)
- V<sub>CC</sub> Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels
   (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Both Digital and Analog Applications: PCI Interface, Differential Signal Interface, Memory Interleaving, Bus Isolation, Low-Distortion Signal Gating
- (1) For additional information regarding the performance characteristics of the CB3Q family, refer to the TI application report, CBT-C, CB3T, and CB3Q Signal-Switch Families, literature number SCDA008.

# DGG, DGV, OR DL PACKAGE (TOP VIEW)

		I	
NC [	1	48	] 1 <u>OE</u>
1B1 [	2	47	] 1A1
1B2 [	3	46	] 1A2
GND[	4	45	GND
1B3 [	5	44	] 1A3
1B4 [	6	43	] 1A4
V <sub>CC</sub> [	7	42	] v <sub>cc</sub>
1B5 [	8	41	] 1A5
1B6 [	9	40	] 1A6
GND[	10	39	GND
1B7 [	11	38	] 1A7
1B8 [	12	37	] 1A8
2B1 [	13	36	2A1
2B2 [	14	35	] 2A2
GND[	15	34	GND
2B3 [	16	33	] 2A3
2B4 [	17	32	2A4
V <sub>CC</sub> [	18	31	] v <sub>cc</sub>
2B5 [	19	30	] 2A5
2B6 [	20	29	] 2A6
GND[	21	28	GND
2B7 [	22	27	] 2A7
2B8 [	23	26	] 2A8
NC [	24	25	2 <u>OE</u>
			l

NC - No internal connection



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments.

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#### DESCRIPTION/ORDERING INFORMATION

The SN74CB3Q16245 is a high-bandwidth FET bus switch utilizing a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance  $(r_{on})$ . The low and flat ON-state resistance allows for minimal propagation delay and supports rail-to-rail switching on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the SN74CB3Q16245 provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

The SN74CB3Q16245 is organized as two 8-bit bus switches with separate output-enable ( $1\overline{OE}$ ,  $2\overline{OE}$ ) inputs. It can be used as two 8-bit bus switches, or as one 16-bit bus switch. When  $\overline{OE}$  is low, the associated 8-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When  $\overline{OE}$  is high, the associated 8-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

#### **ORDERING INFORMATION**

T <sub>A</sub>	PAC	KAGE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
	SSOP – DL	Tube	SN74CB3Q16245DL	CB3Q16245		
	330F - DL	Tape and reel	SN74CB3Q16245DLR	CB3Q10245		
–40°C to 85°C	TOCOD DOC	Tube SN74CB3Q16245DGG		CD2O46245		
	TSSOP – DGG	Tape and reel	SN74CB3Q16245DGGR	- CB3Q16245		
	TVSOP – DGV Tape and reel		SN74CB3Q16245DGVR	BW245		

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

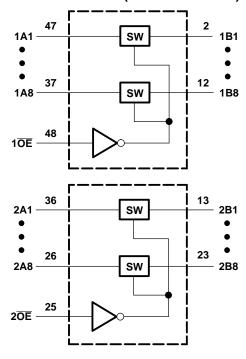
# FUNCTION TABLE (EACH 8-BIT BUS SWITCH)

INPUT OE	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
Н	Z	Disconnect

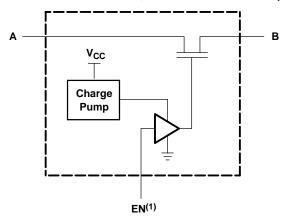


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# **LOGIC DIAGRAM (POSITIVE LOGIC)**

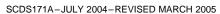


# SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) EN is the internal enable signal applied to the switch.

# SN74CB3Q16245 16-BIT SWITCH 2.5-V/3.3-V LOW-VOLTAGE FET BUS SWITCH





# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
$V_{IN}$	Control input voltage range <sup>(2)(3)</sup>		-0.5	7	V
V <sub>I/O</sub>	Switch I/O voltage range(2)(3)(4)		-0.5	7	V
I <sub>IK</sub>	Control input clamp current	V <sub>IN</sub> < 0		-50	mA
I <sub>I/OK</sub>	I/O port clamp current	V <sub>I/O</sub> < 0		-50	mA
I <sub>I/O</sub>	ON-state switch current <sup>(5)</sup>			±64	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
		DGG package		70	
$\theta_{JA}$	Package thermal impedance (6)	DGV package		58	°C/W
		DL package		63	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground unless otherwise specified.

- (4)  $V_1$  and  $V_0$  are used to denote specific conditions for  $V_{1/0}$ .
- (5)  $I_1$  and  $I_0$  are used to denote specific conditions for  $I_{1/0}$ .
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2.3	3.6	V
\/	$V_{IH}$ High-level control input voltage $ \frac{V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}}{V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}} $	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	5.5	V
VIH		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2	5.5	V
V	V Low lovel control input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	0.7	V
V <sub>IL</sub>	Low-level control input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0	0.8	V
V <sub>I/O</sub>	Data input/output voltage		0	5.5	V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

<sup>(3)</sup> The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



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# Electrical Characteristics(1)

over recommended operating free-air temperature range (unless otherwise noted)

PAI	RAMETER		MIN	TYP <sup>(2)</sup>	MAX	UNIT		
$V_{IK}$		$V_{CC} = 3.6 \text{ V},$	$I_I = -18 \text{ mA}$				-1.8	V
I <sub>IN</sub>	Control inputs	V <sub>CC</sub> = 3.6 V,	V <sub>IN</sub> = 0 to 5.5 V				±1	μΑ
I <sub>OZ</sub> (3)		V <sub>CC</sub> = 3.6 V,	$V_O = 0 \text{ to } 5.5 \text{ V},$ $V_I = 0,$	Switch OFF, $V_{IN} = V_{CC}$ or GND			±1	μΑ
I <sub>off</sub>		$V_{CC} = 0$ ,	$V_0 = 0 \text{ to } 5.5 \text{ V},$	$V_I = 0$			1	μΑ
I <sub>CC</sub>		V <sub>CC</sub> = 3.6 V,	$I_{I/O} = 0$ , Switch ON or OFF,	$V_{IN} = V_{CC}$ or GND		1	2	mA
$\Delta I_{CC}^{(4)}$	Control inputs	$V_{CC} = 3.6 \text{ V},$	One input at 3 V,	Other inputs at $V_{CC}$ or GND			30	μΑ
. (5)	Per control	V <sub>CC</sub> = 3.6 V,	A and B ports open,		0.45	0.05	mA/	
I <sub>CCD</sub> <sup>(5)</sup>	input	Control input switching		0.15	0.25	MHz		
C <sub>in</sub>	Control inputs	V <sub>CC</sub> = 3.3 V,	V <sub>IN</sub> = 5.5 V, 3.3 V, or 0			3.5	5	рF
C <sub>io(OFF)</sub>		V <sub>CC</sub> = 3.3 V,	Switch OFF, $V_{IN} = V_{CC}$ or GND,	$V_{I/O} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or } 0$		4	6	pF
C <sub>io(ON)</sub>		V <sub>CC</sub> = 3.3 V,	Switch ON, $V_{IN} = V_{CC}$ or GND,	$V_{I/O} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or } 0$		10	13	pF
		$V_{CC} = 2.3 \text{ V},$	$V_I = 0$ ,	I <sub>O</sub> = 30 mA		6	8	
r (6)		TYP at $V_{CC} = 2.5 \text{ V}$	$V_{I} = 1.7 \text{ V}, \qquad I_{O} = -15 \text{ mA}$			5	10	Ω
r <sub>on</sub> <sup>(6)</sup>	V 2V		$V_{I} = 0$ , $I_{O} = 30 \text{ mA}$			6	8	22
		$V_{CC} = 3 V$	V <sub>I</sub> = 2.4 V,	$V_1 = 2.4 \text{ V}, \qquad I_0 = -15 \text{ mA}$		5	9	

- $V_{IN}$  and  $I_{IN}$  refer to control inputs.  $V_I$ ,  $V_O$ ,  $I_I$ , and  $I_O$  refer to data pins. All typical values are at  $V_{CC}=3.3~V$  (unless otherwise noted),  $T_A=25^{\circ}C$ . For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.
- This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.
- This parameter specifies the dynamic power-supply current associated with the operating frequency of a single control input (see Figure 2).
- Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = ± 0.2	2.5 V 2 V	V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	(INFOT)	(001701)	MIN	MAX	MIN	MAX	
f <sub>OE</sub> <sup>(1)</sup>	ŌĒ	A or B		10		20	MHz
t <sub>pd</sub> (2)	A or B	B or A		0.18		0.3	ns
t <sub>en</sub>	ŌĒ	A or B	1.5	8	1.5	7	ns
t <sub>dis</sub>	ŌĒ	A or B	1	8	1	7	ns

- Maximum toggle frequency for  $\overline{OE}$  control input (V<sub>O</sub> > V<sub>CC</sub>, V<sub>I</sub> = 5 V, R<sub>L</sub>  $\geq$  1 M $\Omega$ , C<sub>L</sub> = 0) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).



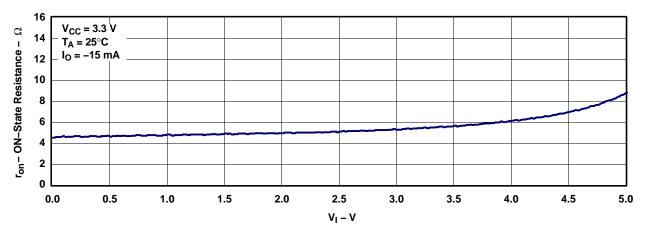


Figure 1. Typical ron vs VI

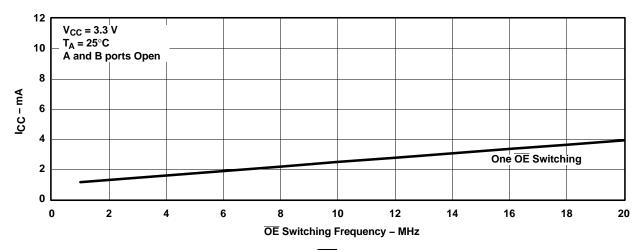
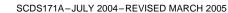
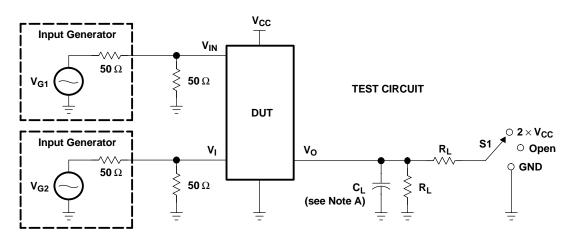


Figure 2. Typical I<sub>CC</sub> vs  $\overline{OE}$  Switching Frequency

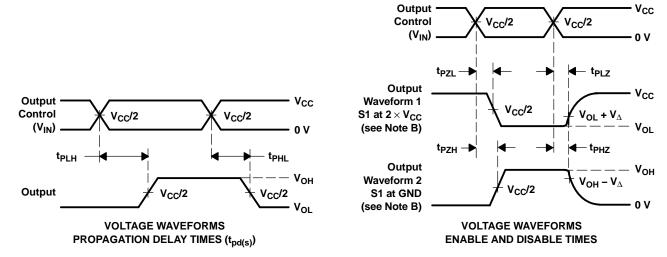




## PARAMETER MEASUREMENT INFORMATION



TEST	V <sub>CC</sub>	S1	R <sub>L</sub>	VI	CL	$\mathbf{V}_{\Delta}$
t <sub>pd(s)</sub>	2.5 V $\pm$ 0.2 V	Open	<b>500</b> Ω	V <sub>CC</sub> or GND	30 pF	
F(-)	3.3 V $\pm$ 0.3 V	Open	500 Ω	V <sub>CC</sub> or GND	50 pF	
t <sub>PLZ</sub> /t <sub>PZL</sub>	2.5 V $\pm$ 0.2 V	2×V <sub>CC</sub>	500 Ω	GND	30 pF	0.15 V
TPLZ/TPZL	3.3 V $\pm$ 0.3 V	2×V <sub>CC</sub>	500 Ω	GND	50 pF	0.3 V
4 /4	2.5 V ± 0.2 V	GND	500 Ω	V <sub>CC</sub>	30 pF	0.15 V
t <sub>PHZ</sub> /t <sub>PZH</sub>	3.3 V $\pm$ 0.3 V	GND	500 Ω	V <sub>CC</sub>	50 pF	0.3 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_{O}$  = 50  $\Omega_{t}$   $t_{f} \leq$  2.5 ns.  $t_{f} \leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Test Circuit and Voltage Waveforms







#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74CB3Q16245DGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q16245DGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q16245DGVRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q16245DGVRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3Q16245DLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q16245DGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q16245DGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q16245DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q16245DLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3Q16245DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

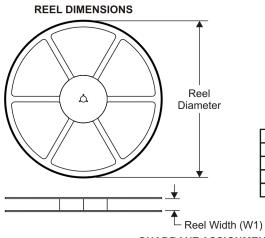
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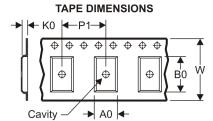
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# PACKAGE MATERIALS INFORMATION

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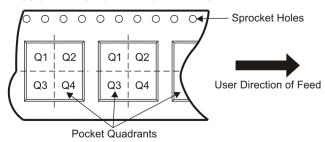
# TAPE AND REEL INFORMATION





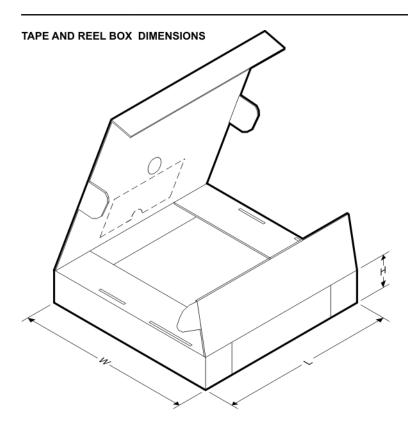
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3Q16245DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74CB3Q16245DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74CB3Q16245DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

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\*All dimensions are nominal

7 III GITTIOTIOTOTIO GITO TIOTITIGI							
Device Package Type		e Package Drawing Pins		SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3Q16245DGGR	TSSOP	DGG	48	2000	346.0	346.0	41.0
SN74CB3Q16245DGVR	TVSOP	DGV	48	2000	346.0	346.0	33.0
SN74CB3Q16245DLR	SSOP	DL	48	1000	346.0	346.0	49.0

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74CB3Q16245DGGR	Active	Production	TSSOP (DGG)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16245
SN74CB3Q16245DGVR	Active	Production	TVSOP (DGV)   48	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	BW245
SN74CB3Q16245DL	Active	Production	SSOP (DL)   48	25   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16245
SN74CB3Q16245DLR	Active	Production	SSOP (DL)   48	1000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CB3Q16245

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

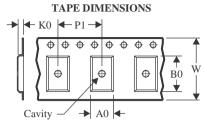
<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





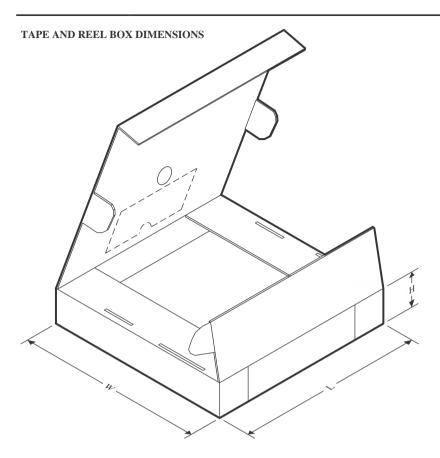
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3Q16245DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74CB3Q16245DGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74CB3Q16245DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1

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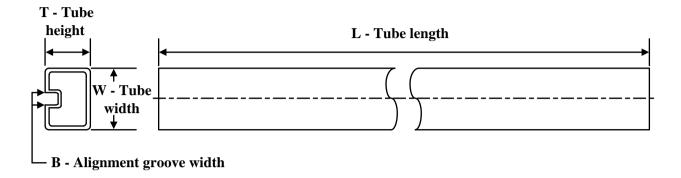


Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74CB3Q16245DGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0	
SN74CB3Q16245DGVR	TVSOP	DGV	48	2000	356.0	356.0	35.0	
SN74CB3Q16245DLR	SSOP	DL	48	1000	367.0	367.0	55.0	

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



	Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
ı	SN74CB3Q16245DL	DL	SSOP	48	25	473.7	14.24	5110	7.87

# DGV (R-PDSO-G\*\*)

## 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

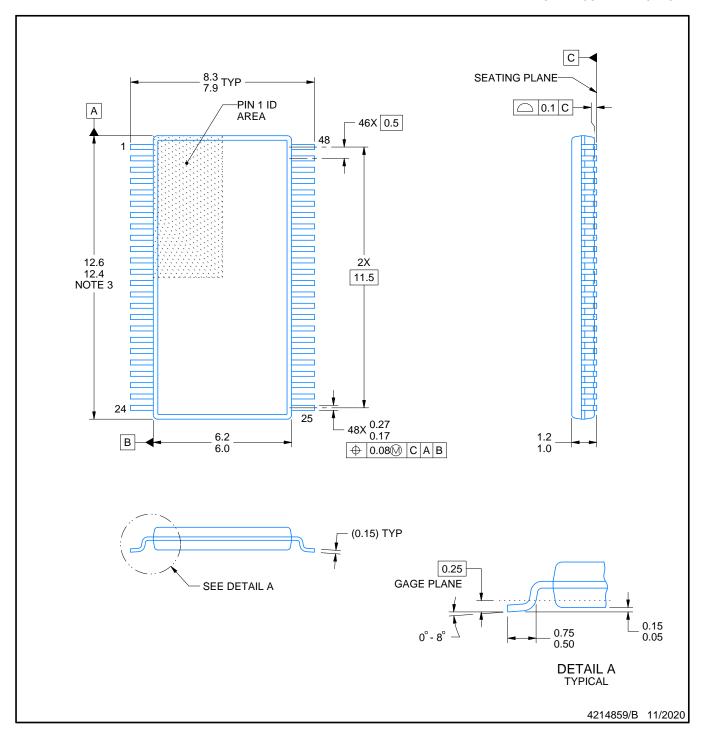
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SMALL OUTLINE PACKAGE



## NOTES:

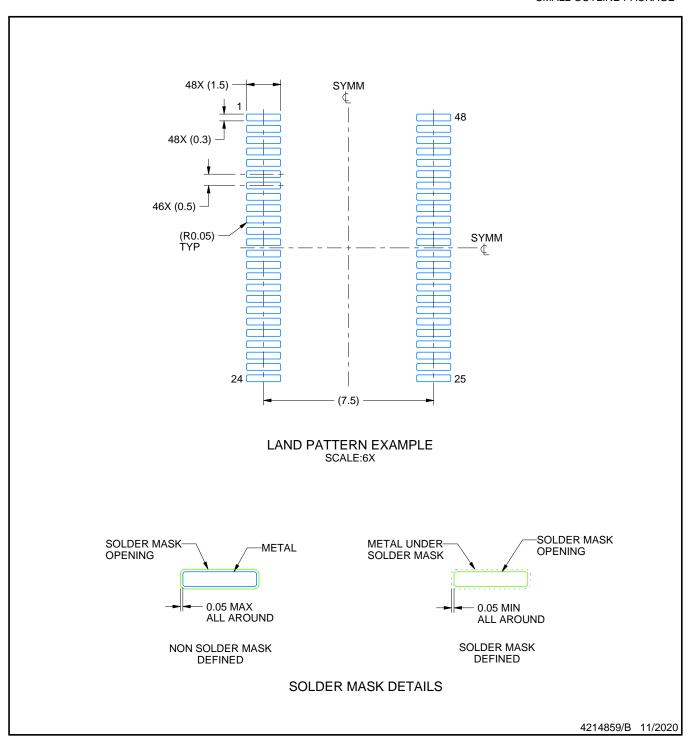
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

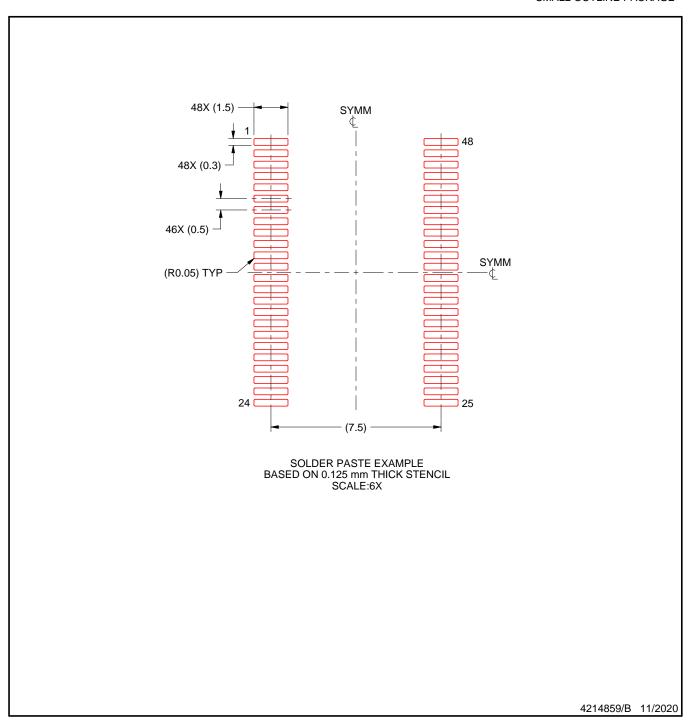


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# DGG (R-PDSO-G\*\*)

# PLASTIC SMALL-OUTLINE PACKAGE

#### **48 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

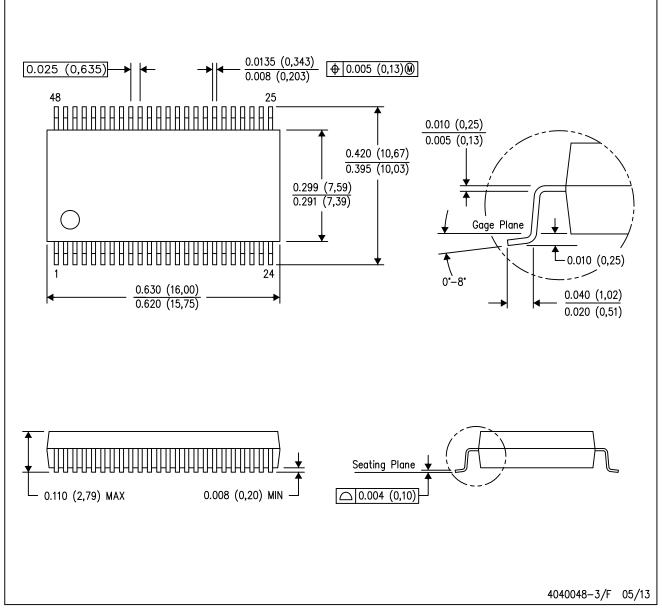
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

# DL (R-PDSO-G48)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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